

## Features

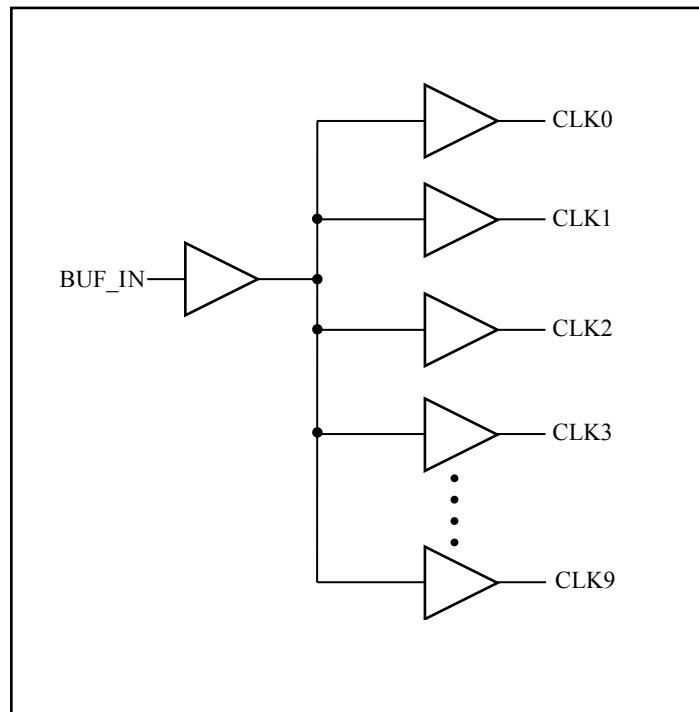
- High-speed, low-noise, non-inverting 1:10 buffer
- Maximum Frequency up to 250 MHz
- Low output skew < 60ps
- Low duty cycle distortion < 200ps
- Low propagation delay < 2.0ns
- Multiple V<sub>DD</sub>, GND pins for noise reduction
- 1.8V or 2.5V supply voltage
- Packages (Pb-free & Green): 20-pin, TSSOP (L20)  
20-pin, SSOP (H20)

## Description

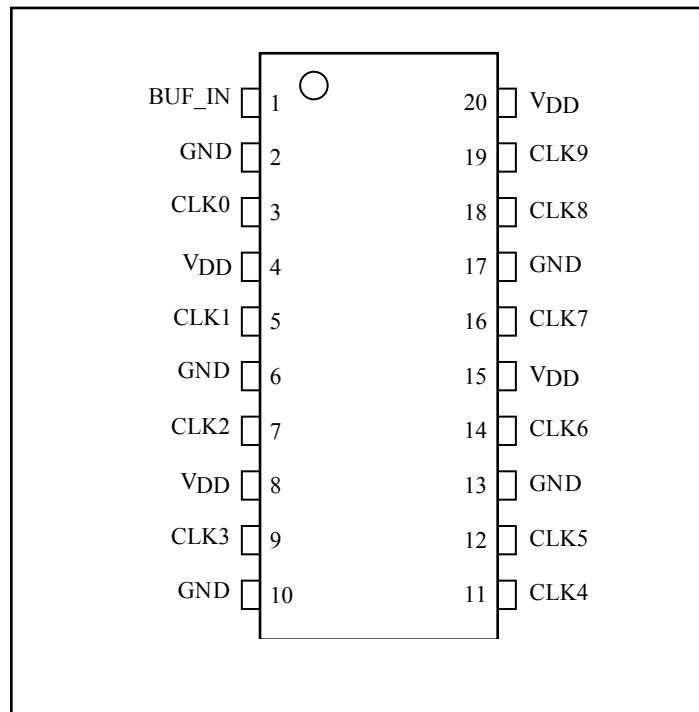
The PI6C10807 is a 1.8V, or 2.5V high-speed, low-noise 1:10 non-inverting clock buffer. The key goal in designing the PI6C10807 is to target networking applications that require low-skew, low-jitter, and high-frequency clock distribution.

Providing output-to-output skew as low as 60ps, the PI6C10807 is an ideal clock distribution device for synchronous systems. Designing synchronous networking systems requires a tight level of skew from a large number of outputs.

## Block Diagram



## Pin Configuration



## Pin Description

Pin Name	Description
BUF_IN	Input
CLK [0:9]	Outputs
GND	Ground
V <sub>DD</sub>	Power

**2.5V Absolute Maximum Ratings** (Above which the useful life may be impaired. For user guidelines only, not tested.)

Storage Temperature.....	-65°C to +150°C
V <sub>DD</sub> Voltage .....	-0.5V to +3.6V
Output Voltage (max. 3.6V) .....	-0.5V to V <sub>DD</sub> +0.5V
Input Voltage (max 3.6V).....	-0.5V to V <sub>DD</sub> +0.5V

**Note:** Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

**2.5V DC Characteristics** (Over Operating Range: V<sub>DD</sub> = 2.5V ± 0.2V, T<sub>A</sub> = -40° to 85°C)

Parameters	Description	Test Conditions <sup>(1)</sup>		Min.	Typ. <sup>(2)</sup>	Max.	Units
V <sub>DD</sub>	Supply Voltage			2.3	2.5	2.7	
V <sub>IH</sub>	Input HIGH Voltage	Logic HIGH level		1.7		3.6	V
V <sub>IL</sub>	Input LOW Voltage	Logic LOW level		-0.3		0.7	
I <sub>I</sub>	Input Current	V <sub>DD</sub> = Max, Vin = V <sub>DD</sub> or GND	I pin			15	µA
V <sub>OH</sub>	Output High Voltage	V <sub>DD</sub> = Min., V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -1mA	2.0			V
			I <sub>OH</sub> = -2mA	1.7			
			I <sub>OH</sub> = -8mA	1.7			
V <sub>OL</sub>	Output LOW Voltage	V <sub>DD</sub> = Min., V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 1mA			0.1	V
			I <sub>OL</sub> = 2mA			0.2	
			I <sub>OL</sub> = 8mA			0.2	

**Notes:**

1. For Max. or Min. conditions, use appropriate operating range values.
2. Typical values are at V<sub>CC</sub> = 2.5V, +25°C ambient and maximum loading.

**2.5V AC Characteristics** (Over Operating Range: V<sub>DD</sub> = 2.5V ± 0.2V, T<sub>A</sub> = -40° to 85°C)

Parameters	Description	Test Conditions <sup>(1)</sup>	Min.	Typ	Max.	Units
F <sub>IN</sub>	Input Frequency		0		250	MHz
t <sub>R</sub> /t <sub>F</sub>	CLKn Rise/Fall Time	20% to 80%			1.0	ns
t <sub>PLH</sub> , t <sub>PHL</sub> <sup>(2)</sup>	Propagation Delay BUF_IN to CLKn	CL = 5pF, 125 MHz Outputs are measured @ V <sub>DD</sub> /2	1.0	1.5	2.0	ps
	Output to Output Skew between any two outputs of the same device @ same transition				60	
	Pulse Skew between opposite transitions (t <sub>PHL</sub> -t <sub>PLH</sub> ) of the same output		100	200		
	Part to Part Skew between two identical outputs of different parts on the same board <sup>(4)</sup>				300	
t <sub>dc_in</sub>	Duty Cycle In @ Ins edge rate		45		55	%
t <sub>dc_out</sub>	Duty Cycle Out		40		60	

**Notes:**

1. See test circuit and waveforms.
2. Minimum limits are guaranteed but not tested on Propagation Delays.
3. Skew measured at worst case temperature (max. temp).
4. Identical conditions: loading, transitions, supply voltage, temperature, package type and speed grade.

**1.8V Absolute Maximum Ratings** (Above which the useful life may be impaired. For user guidelines only, not tested.)

Storage Temperature.....	-65°C to +150°C
V <sub>DD</sub> Voltage .....	-0.5V to +2.5V
Output Voltage (max 2.5V) .....	-0.5V to V <sub>DD</sub> +0.5V
Input Voltage (max 2.5V) .....	-0.5V to V <sub>DD</sub> +0.5V

**Note:** Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

**1.8V DC Characteristics** (Over Operating Range: V<sub>DD</sub> = 1.8V ± 0.15V, T<sub>A</sub> = -40° to 85°C)

Parameters	Description	Test Conditions <sup>(1)</sup>		Min.	Typ. <sup>(2)</sup>	Max.	Units
V <sub>DD</sub>	Supply Voltage			1.65	1.8	1.95	
V <sub>IH</sub>	Input HIGH Voltage	Logic HIGH level		1.1		2.7	V
V <sub>IL</sub>	Input LOW Voltage	Logic LOW level		-0.3		0.35*V <sub>DD</sub>	
I <sub>I</sub>	Input Current <sup>(3)</sup>	V <sub>DD</sub> = Max, V <sub>IN</sub> = V <sub>DD</sub> or GND	I pin			15	µA
V <sub>OH</sub>	Output High Voltage	V <sub>DD</sub> = Min., V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -2mA	1.35			V
			I <sub>OH</sub> = -8mA	1.2			
V <sub>OL</sub>	Output LOW Voltage	V <sub>DD</sub> = Min., V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 2mA			0.1	
			I <sub>OL</sub> = -8mA			0.2	

**Notes:**

- For Max. or Min. conditions, use appropriate operating Vdd and Ta values.
- Typical values are at V<sub>CC</sub> = 1.8V, +25°C ambient and maximum loading.
- This parameter is determined by device characterization but is not production tested.

**1.8V AC Characteristics** (Over Operating Range: V<sub>DD</sub> = 1.8V ± 0.15V, T<sub>A</sub> = -40° to 85°C)

Parameters	Description	Test Conditions <sup>(1)</sup>	Min.	Typ	Max.	Units
F <sub>IN</sub>	Input Frequency		0		180	MHz
t <sub>R</sub> /t <sub>F</sub>	CLKn Rise/Fall Time	20% to 80%			1.0	ns
t <sub>PLH</sub> , t <sub>PHL</sub> <sup>(2)</sup>	Propagation Delay BUF_IN to CLKn		1.0	1.5	2.0	
t <sub>SK(O)</sub> <sup>(3)</sup>	Output to Output Skew between any two outputs of the same device @ same transition				60	ps
t <sub>SK(P)</sub> <sup>(3)</sup>	Pulse Skew between opposite transitions (t <sub>PHL</sub> -t <sub>PLH</sub> ) of the same output	C <sub>L</sub> = 5pF, 125 MHz Outputs are measured @ V <sub>DD</sub> /2	100	200		
t <sub>SK(T)</sub> <sup>(3)</sup>	Part to Part Skew between two identical outputs of different parts on the same board <sup>(4)</sup>				300	
t <sub>dc_in</sub>	Duty Cycle In @ 1 ns edge rate		45		55	
t <sub>dc_out</sub>	Duty Cycle Out		40		60	%

**Notes:**

- See test circuit and waveforms.
- Minimum limits are guaranteed but not tested on Propagation Delays.
- Skew measured at worst case temperature (max. temp).
- Identical conditions: loading, transitions, supply voltage, temperature, package type and speed grade.

### Power Supply Characteristics

Parameters	Description	Test Conditions <sup>(1)</sup>		Min.	Typ. <sup>(2)</sup>	Max.	Units
I <sub>DDQ</sub>	Quiescent Power Supply Current	V <sub>DD</sub> = 2.7V	V <sub>IN</sub> = GND or V <sub>DD</sub>			10	μA
		V <sub>DD</sub> = 1.95V				10	
I <sub>DDn</sub>	Dynamic Power Supply Current per Output	V <sub>DD</sub> = 2.7V	All Outputs Toggling, C <sub>L</sub> = 5pF, F <sub>IN</sub> = 125MHz		1.8		mA
		V <sub>DD</sub> = 1.95V			3.5		
I <sub>DD_TOT</sub>	Total Power Supply Current	V <sub>DD</sub> = 2.7V	V <sub>IN</sub> = V <sub>CC</sub> or GND, All Outputs Toggling, C <sub>L</sub> = 5pF, F <sub>IN</sub> = 125MHz		48		
		V <sub>DD</sub> = 1.95V			35		
ΔI <sub>CC</sub>	Static Supply Current per inputs @ High Level	V <sub>DD</sub> = 2.7V	V <sub>INx</sub> = V <sub>DD</sub> - 0.6V <sup>(3)</sup>			500	μA
		V <sub>DD</sub> = 1.95V	V <sub>INx</sub> = V <sub>DD</sub> - 0.6V <sup>(3)</sup>			450	

**Notes:**

1. For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics.
2. Typical values are at V<sub>CC</sub> = 1.5V, 1.8V or 2.5V, and +25°C ambient.
3. Per TTL driven input (V<sub>IN</sub> = V<sub>DD</sub> - 0.6V); all other inputs at V<sub>CC</sub> or GND.

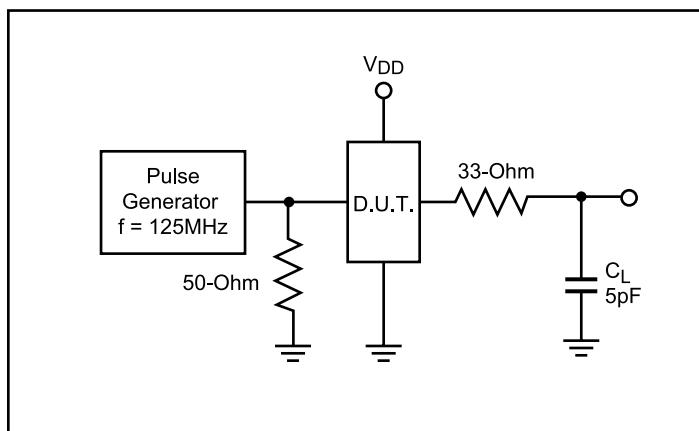
### Capacitance (T<sub>A</sub> = 25°C, f = 1 MHz)

Parameters <sup>(1)</sup>	Description	Test Conditions	Typ	Max.	Units
C <sub>IN</sub>	Input Capacitance	V <sub>IN</sub> = 0V	3.0	4	pF
C <sub>OUT</sub>	Output Capacitance	V <sub>OUT</sub> = 0V	—	6	

**Note:**

1. This parameter is determined by device characterization but is not production tested.

### Test Circuits for All Outputs

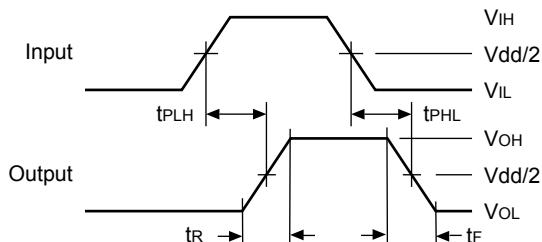


**Definitions:**

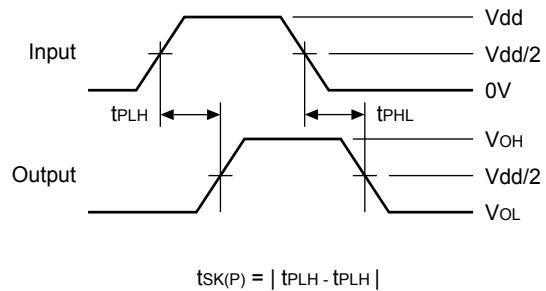
C<sub>L</sub> = Load capacitance: includes jig and probe capacitance.

## Switching Waveforms

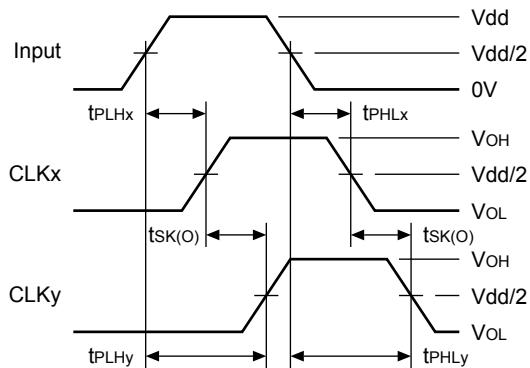
### Propagation Delay



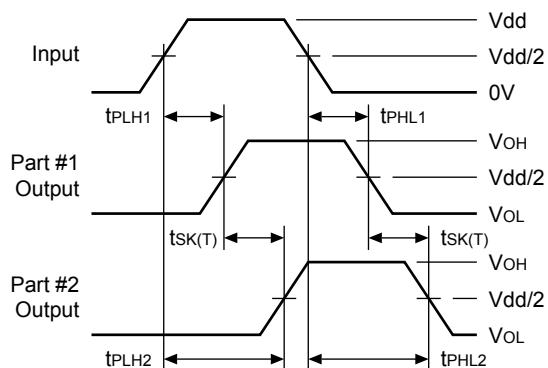
### Pulse Skew – $t_{SK(P)}$

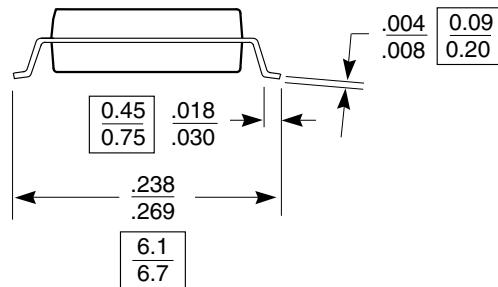
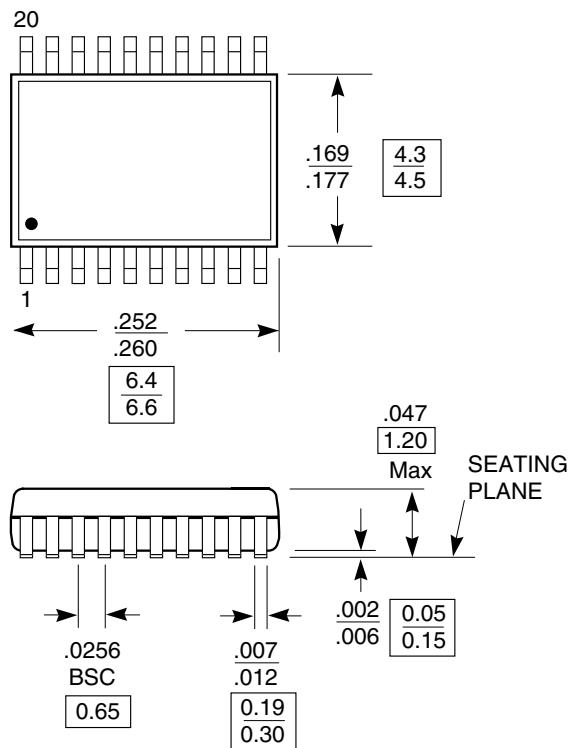


### Output Skew – $t_{SK(O)}$



### Package Skew – $t_{SK(T)}$





**Note:**

- Note:**

  1. Package Outline Exclusive of Mold Flash and Metal Burr
  2. Controlling dimensions in millimeters
  3. Ref: JEDEC MO-153F/AC

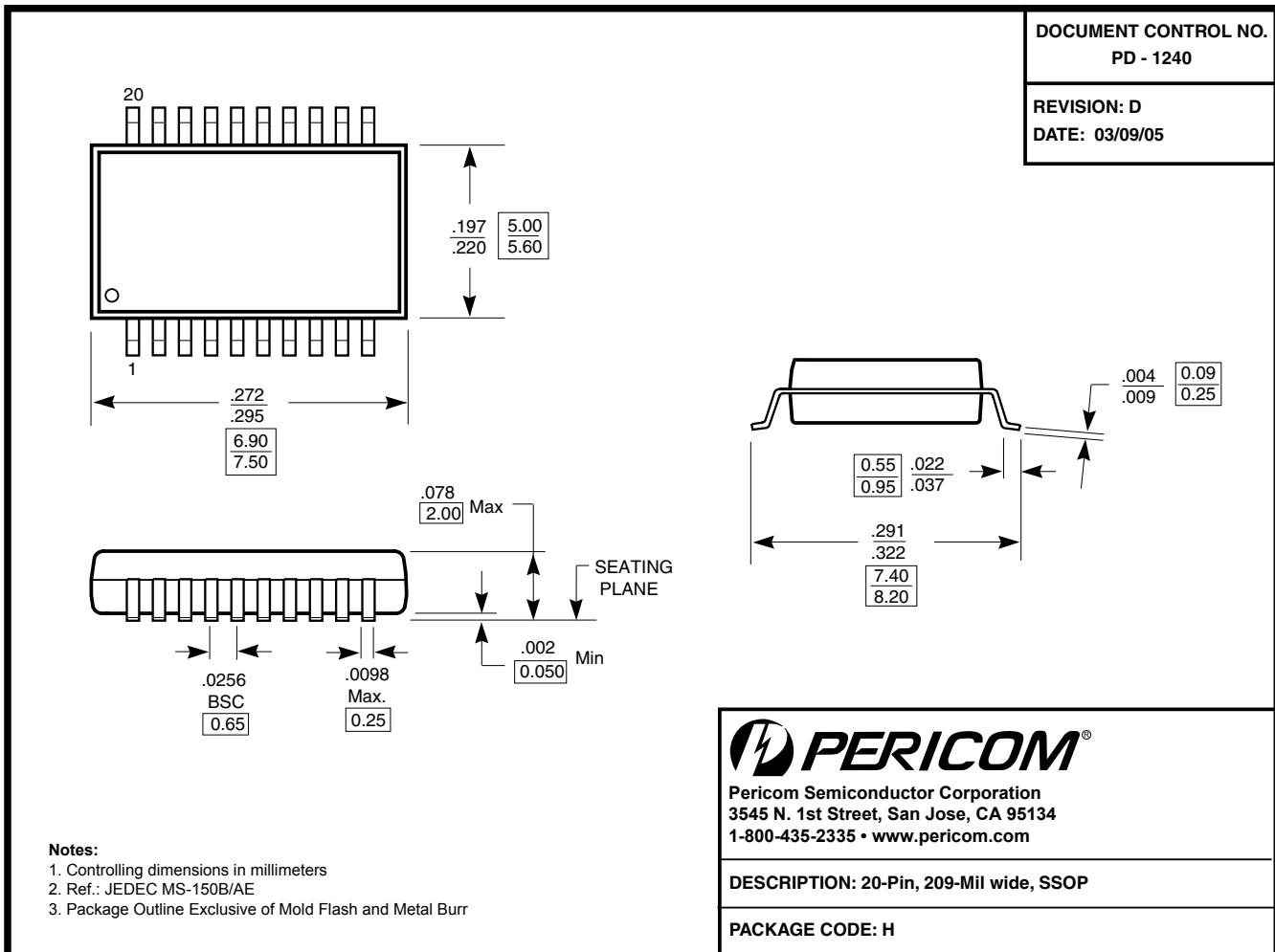
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**Pericom Semiconductor Corporation**  
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**DESCRIPTION:** 20-Pin 173-Mil Wide TSSOP

PACKAGE CODE: L



### Ordering Information<sup>(1-3)</sup>

Ordering Code	Package Code	Package Type
PI6C10807LE	L	Pb-free & Green, 20-pin 173-mil wide TSSOP
PI6C10807HE	H	Pb-free & Green, 20-pin 209-mil wide SSOP

**Notes:**

1. Thermal Characteristics can be found on the web at [www.pericom.com/packaging/](http://www.pericom.com/packaging/)
2. E = Lead-free and Green
3. Adding an X suffix = Tape/Reel